



SRF Reference Sheet

Boltzmann's constant

$$k_B = 1.380649 \times 10^{-23} \text{ m}^2 \text{ s}^{-2} \text{ K}^{-1} \text{ Vacuum}$$

$$\text{permeability } \mu_0 = 1.25663706212 \text{ N A}^{-2}$$

$$\text{Planck constant } h = 6.62607015 \times 10^{-34} \text{ J Hz}^{-1}$$

$$\text{Electron charge } e = 1.60217663 \times 10^{-19} \text{ C}$$

$$\text{Electron mass } m_e = 9.1093837 \times 10^{-31} \text{ kg}$$

Cavity Characteristics

Power Dissipated Per Unit Length

$$\frac{P}{L} = \frac{E_{acc}^2}{R_s Q_0}$$

Accelerating Electric Field

The electric field responsible for acceleration E_{acc} is defined in terms of the voltage difference across the cavity V_c divided by the length of the cavity d .

$$E_{acc} = \frac{V_c}{d}$$

The voltage difference V_c can be calculated from the electric field in the center of the cavity and the resonance frequency ω_0 .

$$V_c = \left| \int_0^d E_z(z) e^{i\omega_0 z/c} dz \right|$$

Quality Factor

The quality factor Q_0 is the ratio of energy stored to power dissipated in the cavity walls defined in terms of the resonance frequency ω_0 , the total energy in the cavity U , and the dissipated power P_c .

$$Q_0 = \frac{\omega_0 U}{P_c}$$

The total energy in the cavity U can be calculated from the electric field E or the magnetic field H .

$$U = \frac{1}{2} \mu_0 \int_V |\mathbf{H}|^2 dv = \frac{1}{2} \epsilon_0 \int_V |\mathbf{E}|^2 dv$$

The power dissipated P_c can be calculated from the magnetic field H and the surface resistance R_s using the following equations.

$$\frac{dP_c}{ds} = \frac{1}{2} R_s |\mathbf{H}|^2$$

$$P_c = \frac{1}{2} R_s \int_S |\mathbf{H}|^2 ds$$

Geometry Factor

The geometry factor G is the component of the quality factor determined by the geometry of the cavity.

$$G = \frac{\omega_0 \mu_0 \int_V |\mathbf{H}|^2 dv}{\int_S |\mathbf{H}|^2 ds}$$

The quality factor can be written in terms of the geometry factor.

$$Q_0 = \frac{\omega_0 \mu_0 \int_V |\mathbf{H}|^2 dv}{R_s \int_S |\mathbf{H}|^2 ds} = \frac{G}{R_s}$$

Pill-Box Cavity

Consider a Pill Box cavity of length d and radius R . The solutions The lowest frequency mode is

$$E_z = E_0 J_0 \left(\frac{2.405 \rho}{R} \right) e^{-i\omega t}$$

$$H_\phi = -i \frac{E_0}{\eta} \left(\frac{2.405 \rho}{R} \right) e^{-i\omega t}$$

The resonance frequency of such a cavity is

$$\omega_{010} = \frac{2.405 c}{R}$$

Here the nomenclature ω_{010} is related to the number of sign changes E_z in the ϕ , ρ , z directions respectively (cylindrical coordinates). For the TM_{010} pill-box mode, $E_{acc} = 2E_0/\pi$ and the peak fields are

$$E_{pk} = E_0, H_{pk} = \frac{E_0}{\eta} J_1(1.84) = \frac{E_0}{647\Omega}$$

If $d = 10 \text{ cm}$, $R = 7.65 \text{ cm}$, $\omega_0 = 1.5 \text{ GHz}$, $V_c = 1 \text{ MV}$ then

$$U = E_0^2 \frac{\pi \epsilon_0}{2} J_1^2(2.405) d R^2 = 0.54 J$$

$$P_c = \frac{\omega U}{Q_0} = 0.4 W$$

Shunt Impedance

The shunt impedance R_a is an important quantity used to characterize losses.

$$R_a = \frac{V_c^2}{P_c}$$

Another definition for shunt impedance r_a is

$$r_a = \frac{V_c^2}{P'_c}$$

Conductivity

Electrical conductivity denoted σ is defined

$$\mathbf{j} = \sigma \mathbf{E}, \sigma = \frac{n e^2 \tau}{m_e}$$

where \mathbf{j} is the current, \mathbf{E} is the electric field, n is the number of electrons per cubic centimeter, and τ is the average time between collisions.

$$\frac{1}{2} m v^2 = \frac{3}{2} k_B T$$

The average time between collisions decreases with higher temperature so conductivity increases with decreasing temperature.

Thermal Conductivity denoted κ is defined

$$j_p = -\kappa \frac{dT}{dx}$$

due the pauli exclusion principle the relationship between thermal conductivity (from electrons) and electric conductivity is

$$\frac{\kappa}{\sigma} = \frac{\pi^2}{3} \left(\frac{k_B}{e} \right)^2 T$$

Note there is also thermal conductivity from phonons but the contribution is insignificant at low temperatures. The equation for the relationship between thermal conductivity (from electrons) and electric conductivity is

$$\frac{\kappa}{\sigma} = \frac{m v^2 C_v}{3 n e^2}$$

The specific heat equations are

$$C_v = \frac{\pi^2}{2} \left(\frac{k_B T}{\epsilon_F} \right) n k_B$$

$$C_v = \frac{\pi^2}{2} k_B^2 T D(\epsilon)$$

Superconducting specific heat (Δ is the superconducting gap)

$$C_s \propto e^{-\frac{\Delta}{k_B T}}$$

Cooper pair coherence length

$$\xi_0 = \frac{\hbar v_F}{k_B T_c} = \frac{\hbar v_F}{\Delta}$$

BCS theory band gap approximation

$$\frac{\Delta(T)}{\Delta(0)} = \left[\cos \left(\frac{\pi t^2}{2} \right) \right]^{1/2}$$

Fraction of unpaired electrons

$$n_{normal} \propto e^{-\frac{\Delta}{k_B T}}$$

Critical current (maximum superconducting current)

$$J_c = \frac{2en\Delta}{m_e v_F}$$

Surface rf resistance due to a small amount of surface electric field penetration

$$R_s = A_s \omega^2 e^{-\frac{\Delta(0)}{k_B T}}$$

This is why we cool to 2K. Thermal conductivity is related to RRR

$$RRR = 4k_s (W/meterK)$$

Maximum Surface Fields

Page 92 with γ defined for equation (3.26)

$$\frac{\mu_0 H_c^2}{2} = 0.236 \gamma T_c^2$$

$$H_c(T) = H_c(0) \left[1 - \left(\frac{T}{T_c} \right)^2 \right]$$

Type I superconductors have a positive surface energy that prevents magnetic fields from entering until the magnetic field is strong enough to completely break down superconductivity. Type II superconductors have a negative surface energy so there is a smaller critical magnetic field H_{c1} such that the magnetic fields penetrate the superconductor. The Ginzbur-Landau parameter distinguishes between type I and type II parameters defined as

$$\kappa_{GL} = \frac{\lambda_L}{\xi_0}$$

where ξ_0 is the coherence distance and λ_L is the magnetic penetration distance.

$$\kappa_{GL} < \frac{1}{\sqrt{2}} \text{ Type I, } \kappa_{GL} > \frac{1}{\sqrt{2}} \text{ Type II}$$

Φ_0 is the flux quantum defined $\Phi_0 = \frac{h}{2e}$. Flux quantum is related to the critical magnetic fields H_{c1} and H_{c2} (5.12):

$$H_{c2} = \frac{\Phi_0}{2\pi\mu_0\xi_0^2}, \quad H_c = \frac{H_{c2}}{\sqrt{2}\kappa_{GL}}$$

$$H_{c1} \propto \frac{H_c}{\sqrt{2}\kappa_{GL}} \ln(\kappa_{GL}) = \frac{\Phi_0}{4\pi\mu_0\lambda_L^2} \ln(\kappa_{GL})$$

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